

第 15 回 CSIS セミナー  
第 87 回ナノ・スピニン工学研究会  
スピントロニクス国際共同大学院セミナー  
半導体スピントロニクス研究室講演会の開催について

日 時： 平成 28 年 2 月 18 日 (木) 10:30～12:00

場 所： 電気通信研究所 ナノ・スピニン総合研究棟 4 階 401 号室

講 師： Professor Geoffrey Beach

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講演題目： **Spin-Orbitronics: Interfacial Design of Spintronic Materials and Devices**

概 要：

There is great interest in electrically manipulating the magnetization in nanoscale materials for high-performance memory and logic device applications. In this talk I will describe recently-discovered mechanisms, based on symmetry breaking and spin-orbit coupling at interfaces, whereby the magnetization can be controlled using very low currents<sup>1-6</sup> or by a gate voltage alone.<sup>5-8</sup> I will focus on ultrathin transition metal ferromagnets sandwiched between an oxide and a nonmagnetic heavy metal, in which magnetic, electronic and ionic effects at the interface can be exploited in new and unexpected ways.

I first focus on the heavy-metal/ferromagnetic interface, where spin-orbit coupling influences not only spin transport, but the nature of magnetism itself in the ferromagnet. In nonmagnetic heavy metals, spin-orbit coupling leads to a left-right scattering asymmetry such that spin up and spin down electrons pile up on either side of a material when a charge current flows through it. I will show how this spin Hall effect can be used to drive magnetization switching and domain wall motion in an adjacent ferromagnetic film,<sup>1-4</sup> and discuss its enhancement through interface engineering<sup>5</sup>. In these same materials, broken inversion symmetry can lift the chiral degeneracy and generate new topological spin textures such as spin-spirals and skyrmions through the interfacial Dzyaloshinskii-Moriya interaction (DMI). I will show that chiral magnetism can persist at room temperature in common transition metal ferromagnets<sup>3,4</sup>, and discuss the role of DMI in domain wall dynamics<sup>3,4</sup> and spin-orbit torque switching<sup>5</sup>. I then show that DMI in engineered heterostructures can be used to stabilize room-temperature magnetic skyrmions<sup>6</sup>, which have recently been proposed as scalable, thermally-stable bits for advanced spintronics devices. We have demonstrated the ability to generate stable skyrmion lattices and drive trains of individual skyrmions by short current pulses along a

magnetic racetrack at speeds exceeding 100 m/s, opening the door to room-temperature skyrmion spintronics in robust thin-film heterostructures<sup>6</sup>.

Finally, I will turn to the ferromagnet/oxide interface<sup>7-11</sup> and describe our discovery of a new class of magneto-ionic materials,<sup>9,10</sup> in which a gate voltage can be used to electrochemically switch the interfacial oxidation state to realize unprecedented control over magnetic properties. Here we use Pt/Co/Gd<sub>2</sub>O<sub>3-δ</sub> ultrathin film stacks, where Gd<sub>2</sub>O<sub>3-δ</sub> serves as an efficient oxygen ion conductor. I show that the magnetization in the thin Co layer can be switched between perpendicular and in-plane orientations, or quenched entirely, by driving O<sup>2-</sup> towards or away from the Co/GdOx interface with a small gate voltage<sup>10</sup>. I then show that magneto-ionic gates can be used to locally tune magnetic properties to create a magnetic analog of field-effect transistors,<sup>9</sup> and to electrically control spin-orbit torques<sup>11</sup>.

1. S. Emori, D. Bono, and G. S. D. Beach, *Appl. Phys. Lett.* **101**, 042405 (2012).
2. S. Emori, U. Bauer, S.-M. Ahn, E. Martinez, and G. S. D. Beach, *Nature Materials* **12**, 611 (2013).
3. S. Emori, E. Martinez, Kyung-Jin Lee, Hyun-Woo Lee, U. Bauer, S.-M. Ahn, P. Agrawal, D. C. Bono, and G. S. D. Beach, *Physical Review B* **90**, 184427 (2014).
4. N. Perez, E. Martinez, L. Torres, S.-H. Woo, S. Emori, and G. S. D. Beach, *Appl. Phys. Lett.* **104**, 092403 (2014)
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6. S. Woo, K. Litzius, B. Krüger, M.-Y. Im, L. Caretta, K. Richter, M. Mann, A. Krone, R. Reeve, M. Weigand, P. Agrawal, P. Fischer, M. Kläui, and G. S. D. Beach, *Nature Materials* *in press* (2016); arXiv:1502.07376
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8. U. Bauer, S. Emori, and G. S. D. Beach, *Appl. Phys. Lett.* **100**, 192408; *ibid* **101**, 172403 (2012).
9. U. Bauer, S. Emori, and G. S. D. Beach, *Nature Nanotechnology* **8**, 411 (2013).
10. U. Bauer, L. Yao, S. Emori, H. L. Tuller, S. van Dijken, and G. S. D. Beach, *Nature Materials* **14**, 174 (2015)
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